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Fairchild Semiconductor
FDP8443_F085

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FAIRCHILD SEMICONDUCTOR®

March 2009

FDP8443_F085

N-Channel PowerTrench® MOSFET

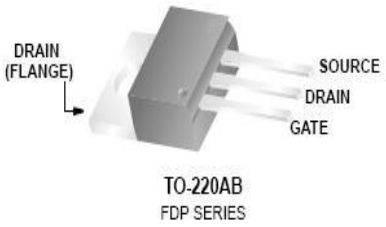
40V, 80A, 3.5mΩ

Features

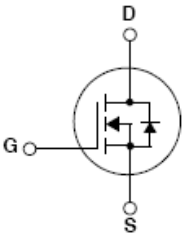
- Typ $r_{DS(on)}$ = 2.7mΩ at V_{GS} = 10V, I_D = 80A
- Typ $Q_{g(10)}$ = 142nC at V_{GS} = 10V
- Low Miller Charge
- Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter / Alternator
- Distributed Power Architecture and VRMs
- Primary Switch for 12V Systems



TO-220AB
FDP SERIES



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain to Source Voltage	40	V
V_{GS}	Gate to Source Voltage	±20	V
I_D	Drain Current Continuous (T_C < 144°C, V_{GS} = 10V)	80	A
	Continuous (T_{amb} = 25°C, V_{GS} = 10V, with $R_{\theta JA}$ = 62°C/W)	20	
	Pulsed	See Figure 4	
E_{AS}	Single Pulse Avalanche Energy (Note 1)	531	mJ
P_D	Power Dissipation	188	W
	Derate above 25°C	1.25	W/°C
T_J, T_{STG}	Operating and Storage Temperature	-55 to +175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case	0.8	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (Note 2)	62	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP8443	FDP8443_F085	TO-220AB	Tube	N/A	50 units

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
B_{VDSS}	Drain to Source Breakdown Voltage	I_D = 250μA, V_{GS} = 0V	40	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 32V, V_{GS} = 0V	-	-	1	μA
		V_{DS} = 32V, V_{GS} = 0V, T_C = 150°C	-	-	250	
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±20V	-	-	±100	nA
On Characteristics						
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250μA	2	2.8	4	V
$r_{DS(on)}$	Drain to Source On Resistance	I_D = 80A, V_{GS}= 10V	-	2.7	3.5	mΩ
		I_D = 80A, V_{GS}= 10V, T_J = 175°C	-	4.7	6.1	
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 25V, V_{GS} = 0V, f = 1MHz	-	9310	-	pF
C_{oss}	Output Capacitance		-	800	-	pF
C_{rss}	Reverse Transfer Capacitance		-	510	-	pF
R_G	Gate Resistance	V_{GS} = 0.5V, f = 1MHz	-	0.9	-	Ω
$Q_{g(TOT)}$	Total Gate Charge at 10V	V_{GS} = 0 to 10V, V_{DD} = 20V, I_D = 35A, I_g = 1mA	-	142	185	nC
$Q_{g(TH)}$	Threshold Gate Charge	V_{GS} = 0 to 2V, V_{DD} = 20V, I_D = 35A, I_g = 1mA	-	17.5	23	nC
Q_{gs}	Gate to Source Gate Charge	V_{DD} = 20V, I_D = 35A, I_g = 1mA	-	36	-	nC
Q_{gs2}	Gate Charge Threshold to Plateau	V_{DD} = 20V, I_D = 35A, I_g = 1mA	-	18.8	-	nC
Q_{gd}	Gate to Drain “Miller“ Charge	V_{DD} = 20V, I_D = 35A, I_g = 1mA	-	32	-	nC

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Switching Characteristics (V_{GS} = 10V)						
t_{on}	Turn-On Time	V_{DD} = 20V, I_D = 35A V_{GS} = 10V, R_{GS} = 2Ω	-	-	58	ns
$t_{d(on)}$	Turn-On Delay Time		-	18.4	-	ns
t_r	Rise Time		-	17.9	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	55	-	ns
t_f	Fall Time		-	13.5	-	ns
t_{off}	Turn-Off Time		-	-	109	ns
Drain-Source Diode Characteristics						
V_{SD}	Source to Drain Diode Voltage	I_{SD} = 35A	-	0.8	1.25	V
		I_{SD} = 15A	-	0.8	1.0	
t_{rr}	Reverse Recovery Time	I_{SD} = 35A, dI_{SD}/dt = 100A/μs	-	42	55	ns
Q_{rr}	Reverse Recovery Charge		-	48	62	nC

Notes:
1: Starting T_J = 25°C, L = 0.26mH, I_{AS} = 64A.
2: Pulse width = 100s.

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/
All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

Typical Characteristics

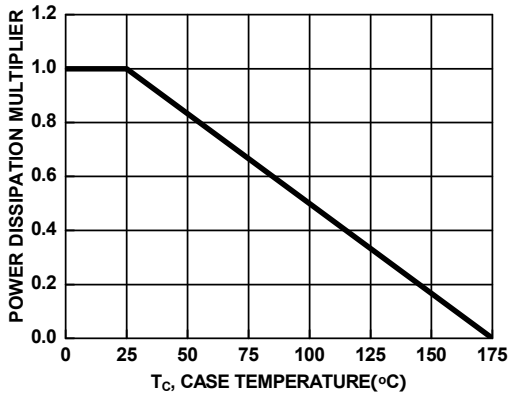


Figure 1. Normalized Power Dissipation vs Case Temperature

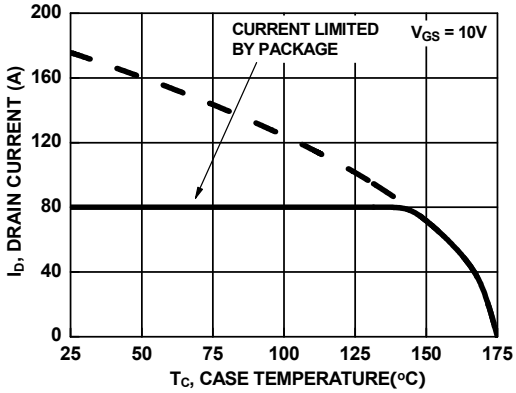


Figure 2. Maximum Continuous Drain Current vs Case Temperature

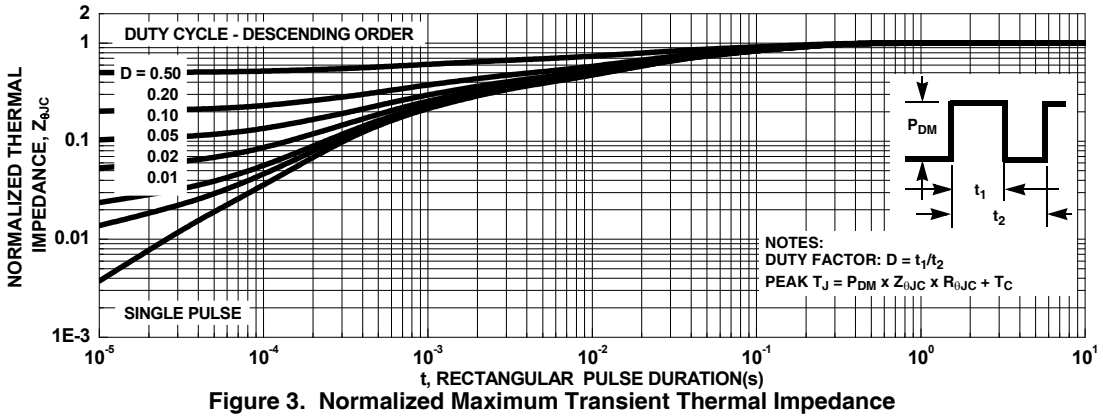


Figure 3. Normalized Maximum Transient Thermal Impedance

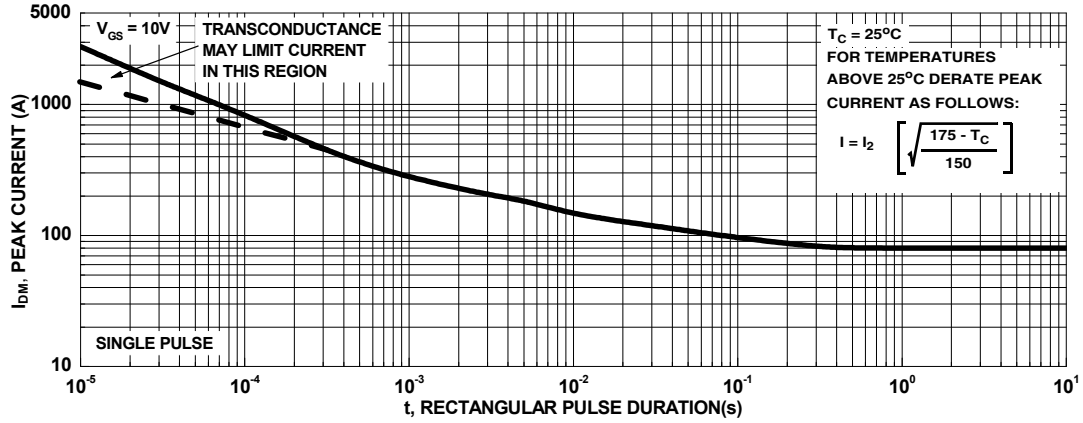


Figure 4. Peak Current Capability

Typical Characteristics

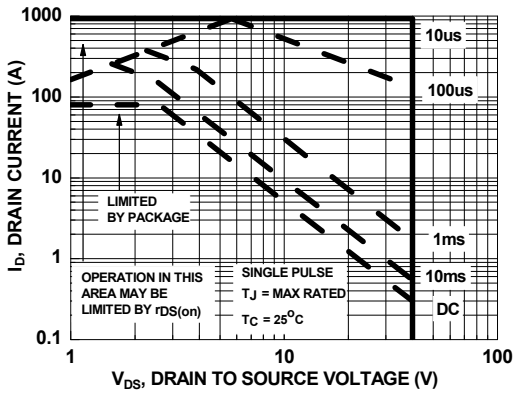
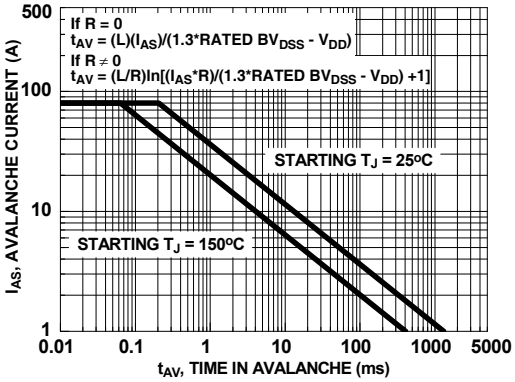


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

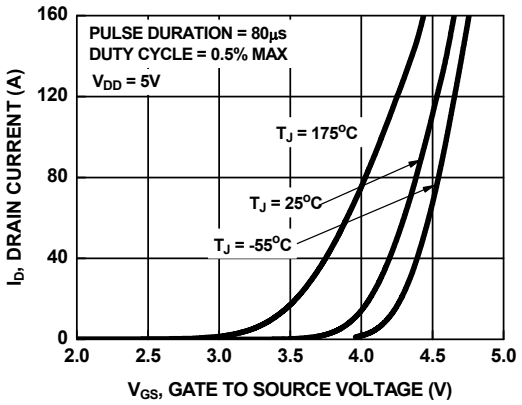


Figure 7. Transfer Characteristics

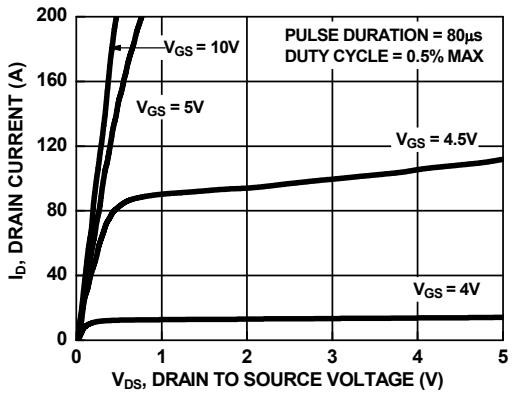


Figure 8. Saturation Characteristics

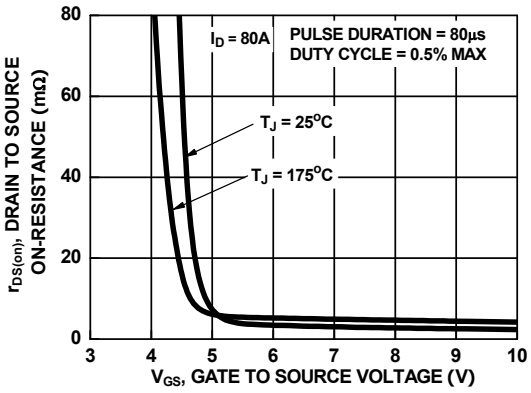


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

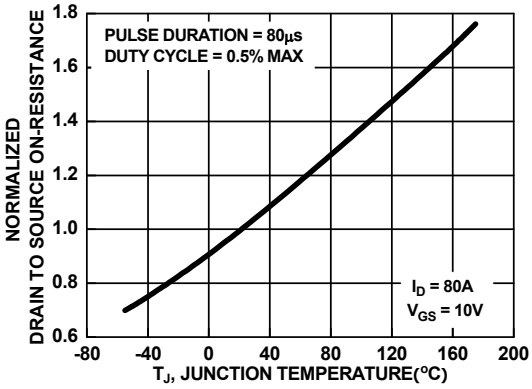


Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature

Typical Characteristics

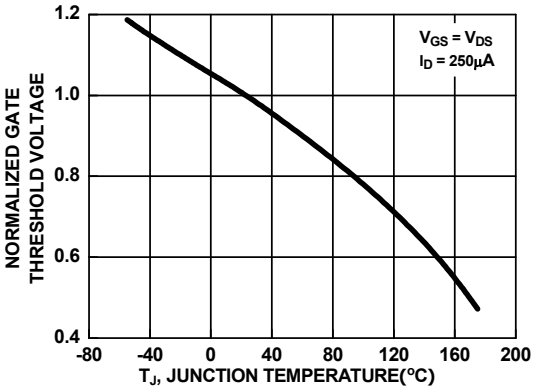


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

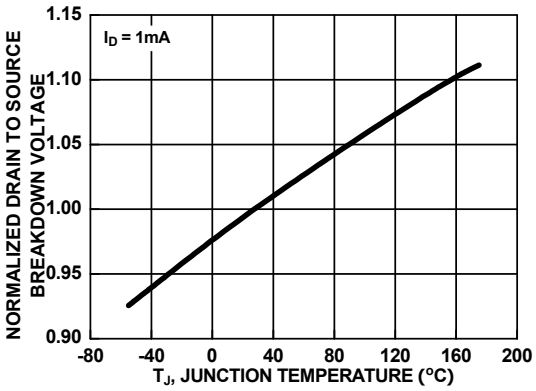


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

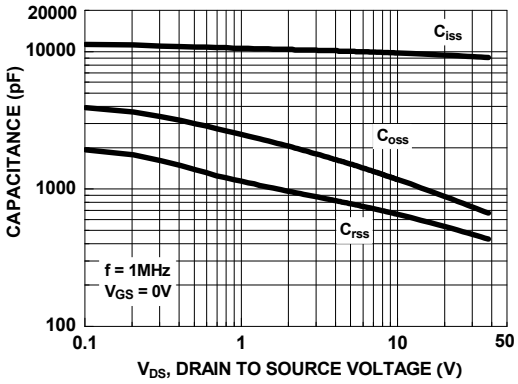


Figure 13. Capacitance vs Drain to Source Voltage

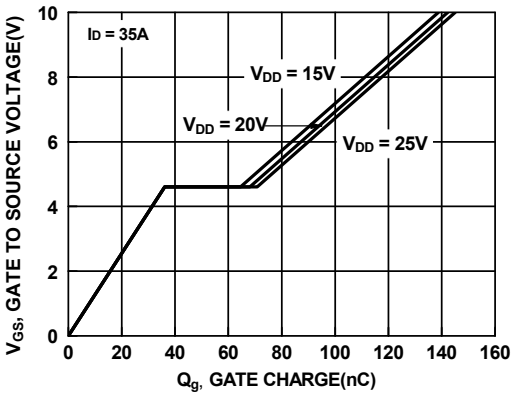


Figure 14. Gate Charge vs Gate to Source Voltage

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